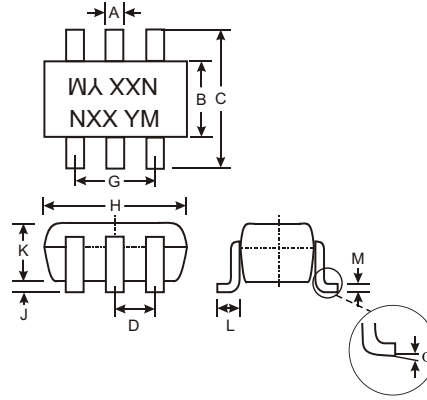


### Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDA)
- Built-In Biasing Resistors

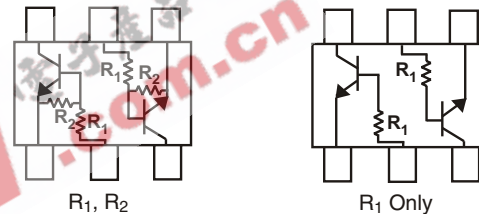
### Mechanical Data

- Case: SOT-26, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 3)
- Weight: 0.015 grams (approx.)
- Ordering Information (See Page 3)



SOT-26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	0.95		
G	1.90		
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
$\alpha$	0°	8°	—
All Dimensions in mm			

P/N	R1	R2	MARKING
DDC124EK	22K $\Omega$	22K $\Omega$	N17
DDC144EK	47K $\Omega$	47K $\Omega$	N20
DDC114YK	10K $\Omega$	47K $\Omega$	N14
DDC123JK	2.2K $\Omega$	47K $\Omega$	N06
DDC114EK	10K $\Omega$	10K $\Omega$	N13
DDC143TK	4.7K $\Omega$	-	N07
DDC114TK	10K $\Omega$	-	N12



SCHMATIC DIAGRAM

### Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage, (3) to (1)	$V_{CC}$	50	V
Input Voltage, (2) to (1)	$V_{IN}$	-10 to +40 -10 to +40 -6 to +40 -5 to +12 -10 to +40 -5 $V_{max}$ -5 $V_{max}$	V
Output Current	$I_o$	30 30 70 100 50 100 100	mA
Output Current	$I_C$ (Max)	100	mA
Power Dissipation (Total)	$P_d$	300	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{\theta JA}$	416.7	$^\circ\text{C/W}$
Operating and Storage and Temperature Range	$T_j, T_{STG}$	-55 to +150	$^\circ\text{C}$

- Note: 1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.  
2. 200mW per element must not be exceeded.

## Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic (DDC143TK & DDC114TK only)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	50	—	—	V	I <sub>C</sub> = 50μA
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	50	—	—	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	5	—	—	V	I <sub>E</sub> = 50μA
Collector Cutoff Current	I <sub>CBO</sub>	—	—	0.5	μA	V <sub>CB</sub> = 50V
Emitter Cutoff Current	I <sub>EBO</sub>	—	—	0.5	μA	V <sub>EB</sub> = 4V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	—	—	0.3	V	I <sub>C</sub> /I <sub>B</sub> = 2.5mA / 0.25mA I <sub>C</sub> /I <sub>B</sub> = 1mA / 0.1mA DDC143TK DDC114TK
DC Current Transfer Ratio	h <sub>FE</sub>	100	250	600	—	I <sub>C</sub> = 1mA, V <sub>CE</sub> = 5V
Input Resistor (R <sub>1</sub> ) Tolerance	ΔR <sub>1</sub>	-30	—	+30	%	—
Gain-Bandwidth Product*	f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = -5mA, f = 100MHz

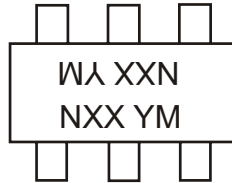
Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDC124EK DDC144EK DDC114YK DDC123JK DDC114EK	V <sub>I(off)</sub>	0.5	1.1	—	V	V <sub>CC</sub> = 5V, I <sub>O</sub> = 100μA
	DDC124EK DDC144EK DDC114YK DDC123JK DDC114EK		—	1.9	3.0		
Output Voltage	DDC124EK DDC144EK DDC114YK DDC123JK DDC114EK	V <sub>O(on)</sub>	—	0.1	0.3	V	I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA I <sub>O</sub> /I <sub>I</sub> = 5mA / 0.25mA I <sub>O</sub> /I <sub>I</sub> = 5mA / 0.25mA I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA
	DDC124EK DDC144EK DDC114YK DDC123JK DDC114EK		—	1.9	3.0		
Input Current	DDC124EK DDC144EK DDC114YK DDC123JK DDC114EK	I <sub>I</sub>	—	—	0.36 0.18 0.88 3.6 0.88	mA	V <sub>I</sub> = 5V
Output Current		I <sub>O(off)</sub>	—	—	0.5	μA	V <sub>CC</sub> = 50V, V <sub>I</sub> = 0V
DC Current Gain	DDC124EK DDC144EK DDC114YK DDC123JK DDC114EK	G <sub>I</sub>	56 68 68 80 30	—	—	—	V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA
Input Resistor (R <sub>1</sub> ) Tolerance		ΔR <sub>1</sub>	-30	—	+30	%	—
Resistance Ratio Tolerance		R <sub>2</sub> /R <sub>1</sub>	-20	—	+20	%	—
Gain-Bandwidth Product*		f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = 5mA, f = 100MHz

\* Transistor - For Reference Only

**Ordering Information** (Note 3)

Device	Packaging	Shipping
DDC124EK-7	SOT-26	3000/Tape & Reel
DDC144EK-7	SOT-26	3000/Tape & Reel
DDC114YK-7	SOT-26	3000/Tape & Reel
DDC123JK-7	SOT-26	3000/Tape & Reel
DDC114EK-7	SOT-26	3000/Tape & Reel
DDC143TK-7	SOT-26	3000/Tape & Reel
DDC114TK-7	SOT-26	3000/Tape & Reel

Notes: 3. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

**Marking Information**

NXX = Product Type Marking Code  
See Sheet 1 Diagrams  
YM = Date Code Marking  
Y = Year ex: N = 2002  
M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

TYPICAL CURVES - DDC123JK  
ONE SECTION

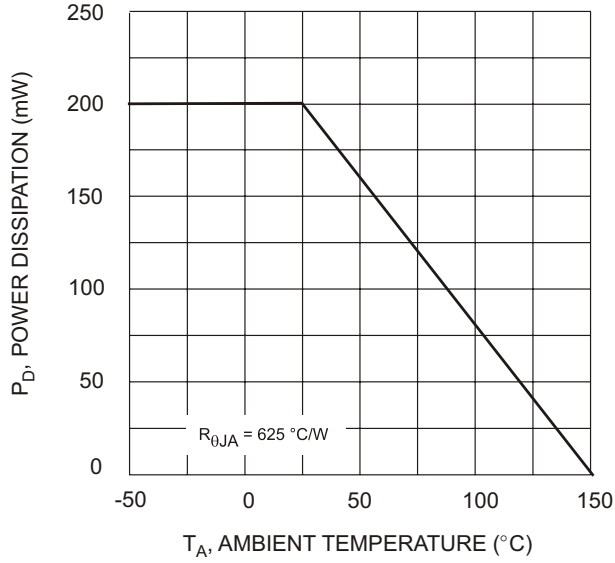


Fig. 1 Derating Curve

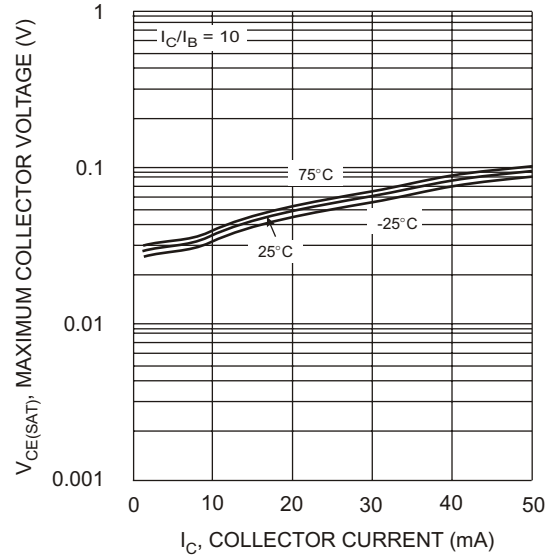


Fig. 2  $V_{CE(SAT)}$  vs.  $I_C$

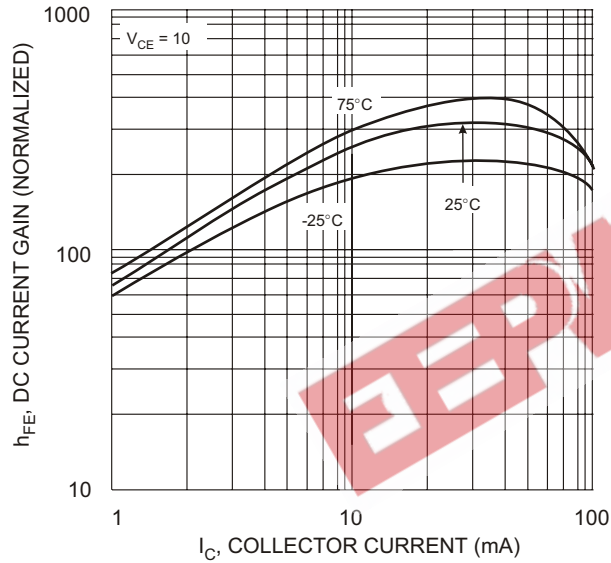


Fig. 3 DC Current Gain

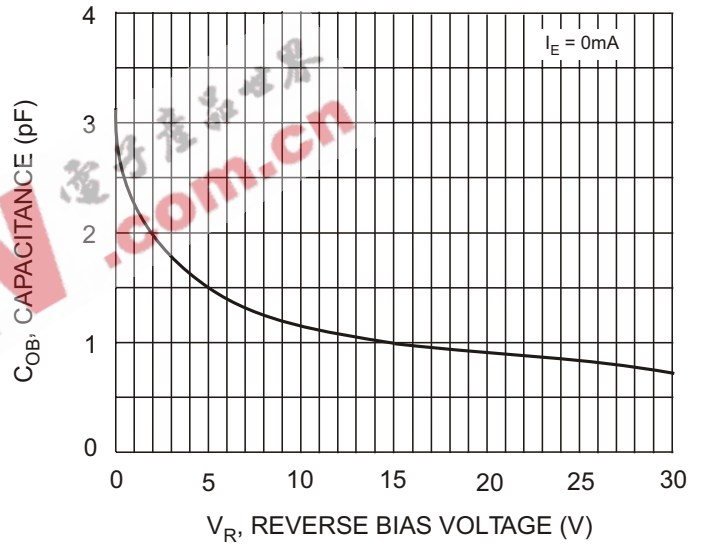


Fig. 4 Output Capacitance

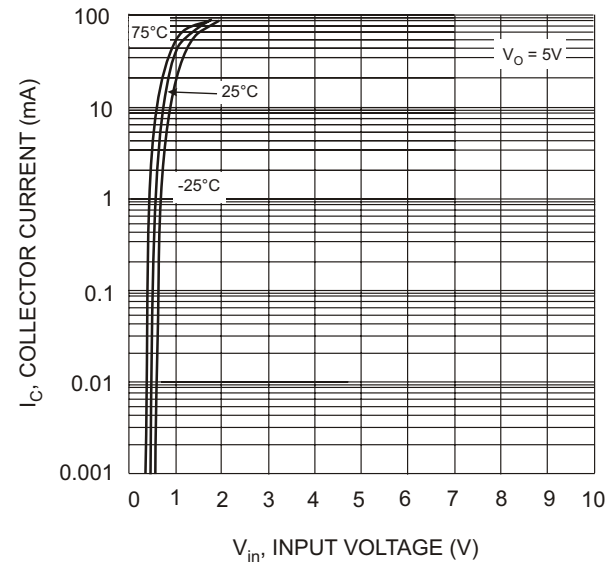


Fig. 5 Collector Current Vs. Input Voltage

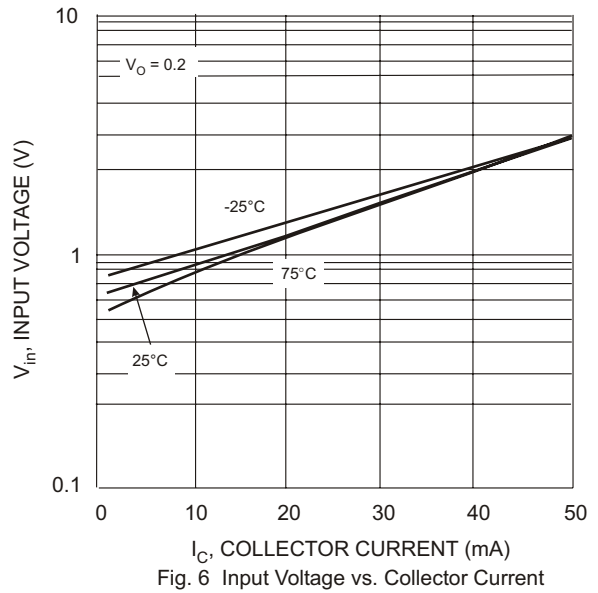


Fig. 6 Input Voltage vs. Collector Current

TYPICAL CURVES - DDC114TK

ONE SECTION

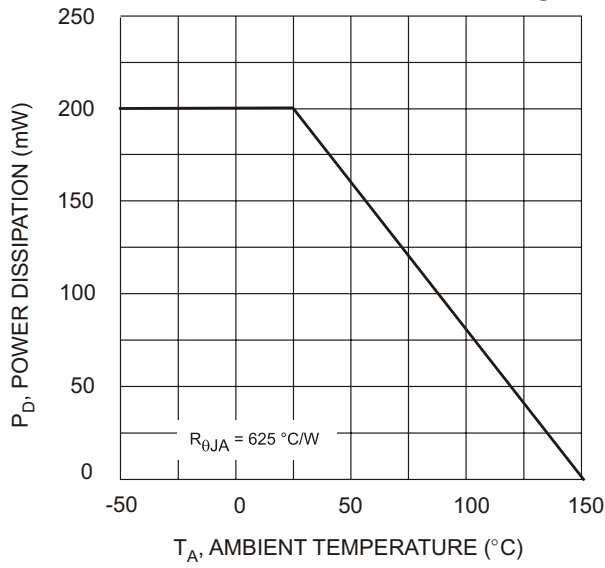


Fig. 1 Derating Curve

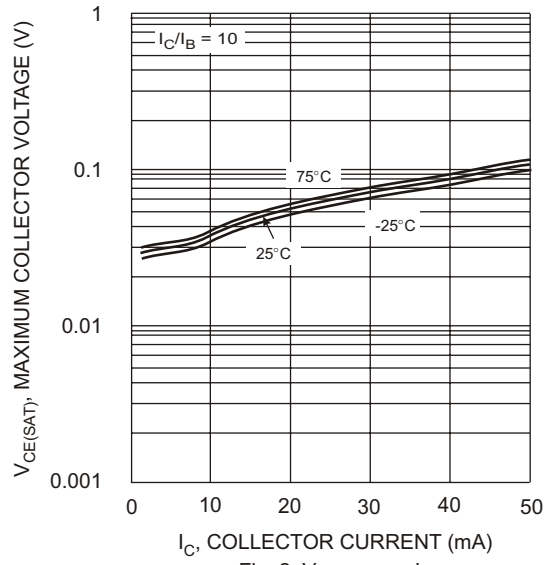


Fig. 2  $V_{CE(SAT)}$  vs.  $I_C$

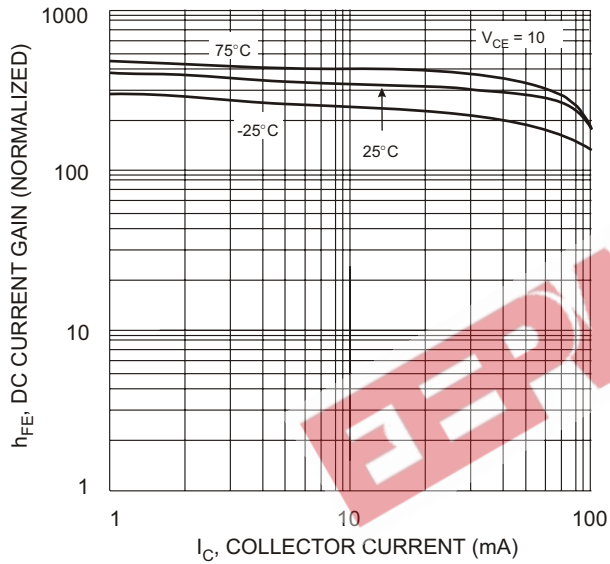


Fig. 3 DC Current Gain

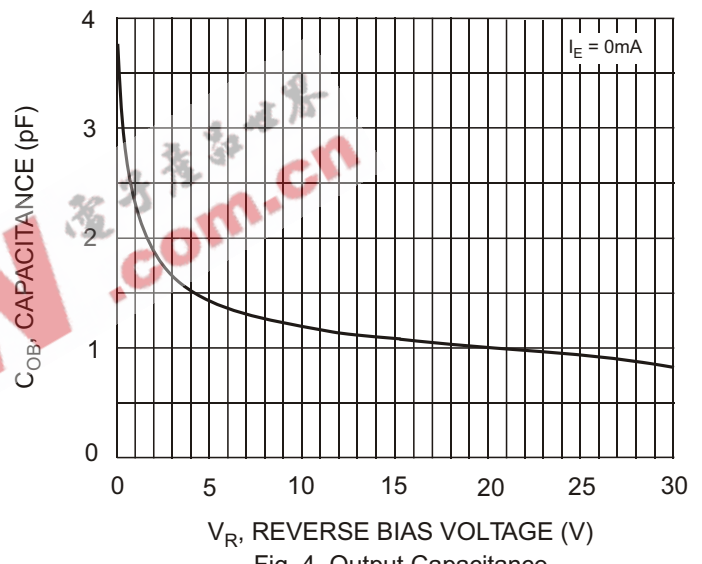


Fig. 4 Output Capacitance

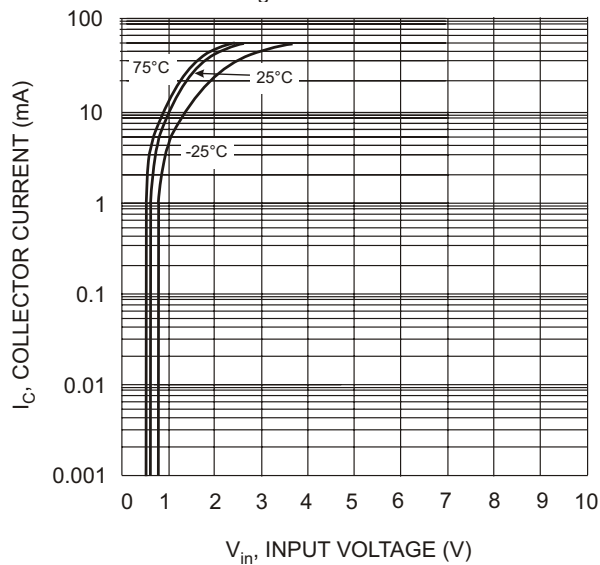


Fig. 5 Collector Current Vs. Input Voltage

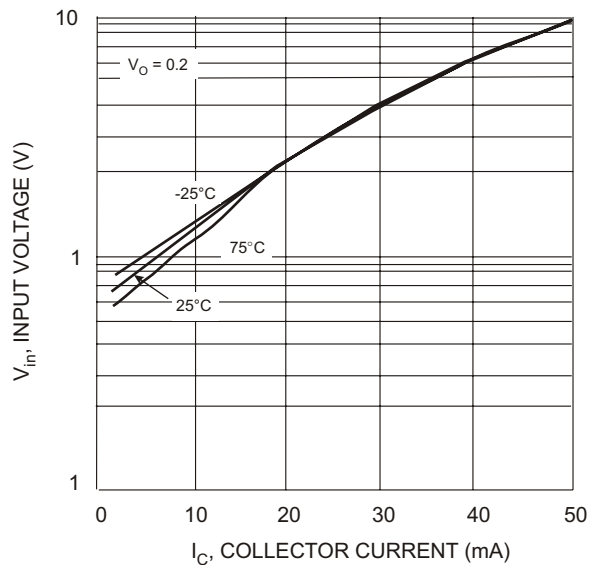


Fig. 6 Input Voltage vs. Collector Current